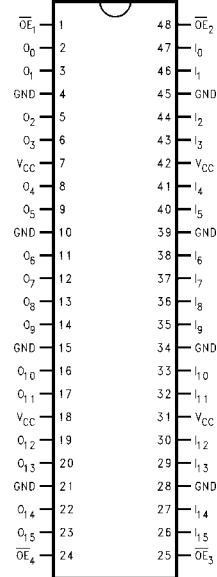
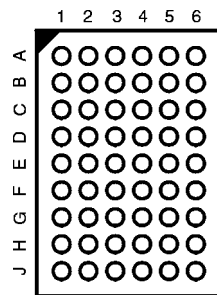


Connection Diagrams

Pin Assignment for SSOP and TSSOP

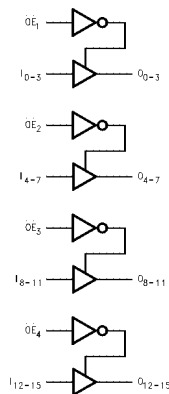


Pin Assignment for FBGA



(Top Thru View)

Logic Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active LOW)
I_0-I_{15}	Inputs
O_0-O_{15}	Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
A	O ₀	NC	$\overline{OE}_1$	$\overline{OE}_2$	NC	I ₀
B	O ₂	O ₁	NC	NC	I ₁	I ₂
C	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I ₄
D	O ₆	O ₅	GND	GND	I ₅	I ₆
E	O ₈	O ₇	GND	GND	I ₇	I ₈
F	O ₁₀	O ₉	GND	GND	I ₉	I ₁₀
G	O ₁₂	O ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
H	O ₁₄	O ₁₃	NC	NC	I ₁₃	I ₁₄
J	O ₁₅	NC	$\overline{OE}_4$	$\overline{OE}_3$	NC	I ₁₅

Truth Table

Inputs		Outputs
$\overline{OE}_1$	I_0-I_3	O_0-O_3
L	L	L
L	H	H
H	X	Z
Inputs		Outputs
$\overline{OE}_2$	I_4-I_7	O_4-O_7
L	L	L
L	H	H
H	X	Z
Inputs		Outputs
$\overline{OE}_3$	I_8-I_{11}	O_8-O_{11}
L	L	L
L	H	H
H	X	Z
Inputs		Outputs
$\overline{OE}_4$	$I_{12}-I_{15}$	$O_{12}-O_{15}$
L	L	L
L	H	H
H	X	Z

H = High Voltage Level
 L = Low Voltage Level
 X = Immaterial
 Z = High Impedance

Functional Description

The LVT16244 and LVTH16244 contain sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4-bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

Absolute Maximum Ratings ^(Note 3)					
Symbol	Parameter	Value	Conditions		Units
V _{CC}	Supply Voltage	−0.5 to +4.6			V
V _I	DC Input Voltage	−0.5 to +7.0			V
V _O	Output Voltage	−0.5 to +7.0	Output in 3-STATE		V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 4)		
I _{IK}	DC Input Diode Current	−50	V _I < GND		mA
I _{OK}	DC Output Diode Current	−50	V _O < GND		mA
I _O	DC Output Current	64	V _O > V _{CC} Output at HIGH State		mA
		128	V _O > V _{CC} Output at LOW State		
I _{CC}	DC Supply Current per Supply Pin	±64			mA
I _{GND}	DC Ground Current per Ground Pin	±128			mA
T _{STG}	Storage Temperature	−65 to +150			°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units	
V _{CC}	Supply Voltage	2.7	3.6	V	
V _I	Input Voltage	0	5.5	V	
I _{OH}	HIGH Level Output Current		−32	mA	
I _{OL}	LOW Level Output Current		64	mA	
T _A	Free Air Operating Temperature	−40	+85	°C	
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V	

Note 3: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 4: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	T _A = −40°C to +85°C		Units	Conditions	
			Min	Max			
V _{IK}	Input Clamp Diode Voltage	2.7		−1.2	V	I _I = −18 mA	
V _{IH}	Input HIGH Voltage	2.7–3.6	2.0		V	V _O ≤ 0.1V or	
V _{IL}	Input LOW Voltage	2.7–3.6		0.8	V	V _O ≥ V _{CC} − 0.1V	
V _{OH}	Output HIGH Voltage	2.7–3.6	V _{CC} − 0.2		V	I _{OH} = −100 μA	
		2.7	2.4			I _{OH} = −8 mA	
		3.0	2.0			I _{OH} = −32 mA	
V _{OL}	Output LOW Voltage	2.7		0.2	V	I _{OL} = 100 μA	
		2.7		0.5		I _{OL} = 24 mA	
		3.0		0.4		I _{OL} = 16 mA	
		3.0		0.5		I _{OL} = 32 mA	
		3.0		0.55		I _{OL} = 64 mA	
I _{I(HOLD)} (Note 5)	Bushold Input Minimum Drive	3.0	75		μA	V _I = 0.8V	
			−75			V _I = 2.0V	
I _{I(OD)} (Note 5)	Bushold Input Over-Drive Current to Change State	3.0	500		μA	(Note 6)	
			−500			(Note 7)	
I _I	Input Current	3.6		10	μA	V _I = 5.5V	
		Control Pins	3.6			±1	V _I = 0V or V _{CC}
			Data Pins	3.6			−5
				1		V _I = V _{CC}	
I _{OFF}	Power Off Leakage Current	0		±100	μA	0V ≤ V _I or V _O ≤ 5.5V	
I _{PU/PO}	Power Up/Down 3-STATE Current	0 – 1.5V		±100	μA	V _O = 0.5V to 3.0V V _I = GND or V _{CC}	
I _{OZL}	3-STATE Output Leakage Current	3.6		−5	μA	V _O = 0.5V	
I _{OZH}	3-STATE Output Leakage Current	3.6		5	μA	V _O = 3.0V	
I _{OZH+}	3-STATE Output Leakage Current	3.6		10	μA	V _{CC} < V _O ≤ 5.5V	

DC Electrical Characteristics (Continued)

Symbol	Parameter	V _{CC} (V)	T _A = -40°C to +85°C		Units	Conditions
			Min	Max		
I _{CCH}	Power Supply Current	3.6		0.19	mA	Outputs High
I _{CCL}	Power Supply Current	3.6		5.0	mA	Outputs Low
I _{CCZ}	Power Supply Current	3.6		0.19	mA	Outputs Disabled
I _{CCZ} ⁺	Power Supply Current	3.6		0.19	mA	V _{CC} ≤ V _O ≤ 5.5V, Outputs Disabled
ΔI _{CC}	Increase in Power Supply Current (Note 8)	3.6		0.2	mA	One Input at V _{CC} - 0.6V Other Inputs at V _{CC} or GND

Note 5: Applies to bushold versions only (LVTH16244).

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 8: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 9)

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			Units	Conditions C _L = 50 pF, R _L = 500Ω
			Min	Typ	Max		
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3		0.8		V	(Note 10)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3		-0.8		V	(Note 10)

Note 9: Characterized in SSOP package. Guaranteed parameter, but not tested.

Note 10: Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

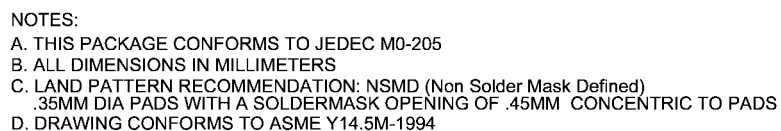
Symbol	Parameter	T _A = -40°C to +85°C C _L = 50 pF, R _L = 500Ω				Units
		V _{CC} = 3.3V ± 0.3V		V _{CC} = 2.7V		
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay Data to Output	1.2	3.5	1.2	3.9	ns
t _{PHL}		1.2	3.5	1.2	3.9	
t _{PZH}	Output Enable Time	1.2	4.0	1.2	5.0	ns
t _{PZL}		1.2	5.0	1.2	6.5	
t _{PHZ}	Output Disable Time	2.0	4.7	2.0	5.2	ns
t _{PLZ}		1.5	4.2	1.5	4.4	
t _{OSHL}	Output to Output Skew (Note 11)		1.0		1.0	ns
t _{OSLH}						

Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Capacitance (Note 12)

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	V _{CC} = 0V, V _I = 0V or V _{CC}	4	pF
C _{OUT}	Output Capacitance	V _{CC} = 3.0V, V _O = 0V or V _{CC}	8	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883, Method 3012.



**54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
Package Number BGA54A**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

